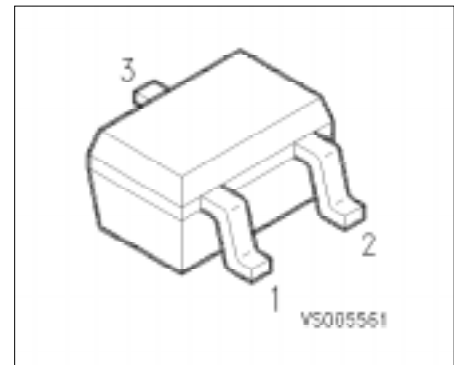


## Silicon Schottky Diode

**BAS 70W**

- General-purpose diodes for high-speed switching
- Circuit protection
- Voltage clamping
- High-level detection and mixing



Type	Ordering Code (tape and reel)	Pin Configuration			Marking	Package <sup>1)</sup>
		1	2	3		
BAS 70-04W	Q62702-A1068	A1	C2	C1/A2	74s	SOT-323
BAS 70-05W	Q62702-A1069	A1	A2	C1/C2	75s	
BAS 70-06W	Q62702-A1070	C1	C2	A1/A2	76s	

### Maximum Ratings

Parameter	Symbol	Values	Unit
Reverse voltage	$V_R$	70	V
Forward current	$I_F$	70	mA
Surge forward current, $t \leq 10$ ms	$I_{FSM}$	100	mA
Total power dissipation $T_S \leq 91$ °C	$P_{tot}$	250	mW
Operating temperature range	$T_{op}$	- 55 ... + 150	°C
Storage temperature range	$T_{stg}$	- 55 ... + 150	°C

### Thermal Resistance

Junction-ambient <sup>1)</sup>	$R_{th JA}$	$\leq 455$	K/W
Junction-soldering point	$R_{th JS}$	$\leq 235$	K/W

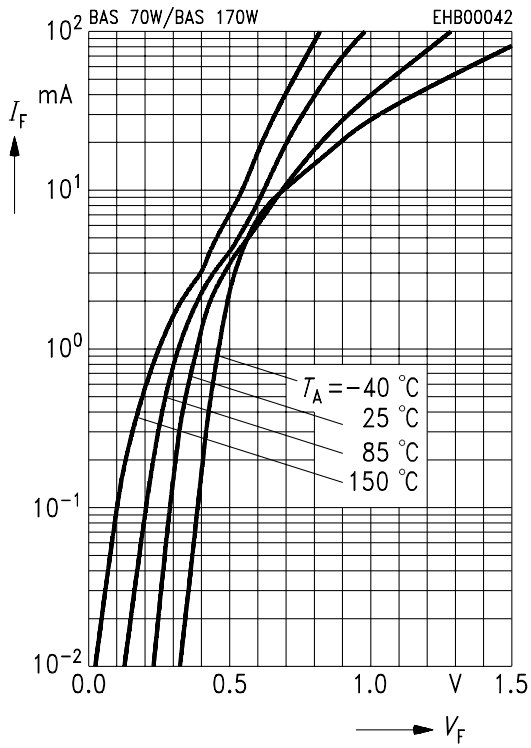
1) Package mounted on an epoxy pcb 40 mm x 40 mm x 1.5 mm/1cm<sup>2</sup> Cu.

## Electrical Characteristics

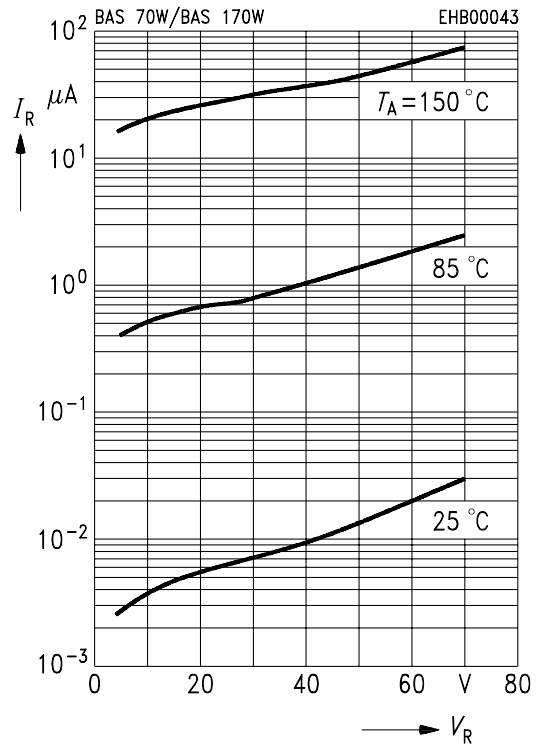
at  $T_A = 25\text{ °C}$ , unless otherwise specified.

Parameter	Symbol	Value			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Breakdown voltage $I_{(BR)} = 10\text{ }\mu\text{A}$	$V_{(BR)}$	70	–	–	V
Forward voltage $I_F = 1\text{ mA}$ $I_F = 10\text{ mA}$ $I_F = 15\text{ mA}$	$V_F$	300 600 750	375 705 880	410 750 1000	mV
Reverse current $V_R = 50\text{ V}$ $V_R = 70\text{ V}$	$I_R$	– –	– –	0.1 10	$\mu\text{A}$
Diode capacitance $V_R = 0\text{ V}, f = 1\text{ MHz}$	$C_T$	–	1.5	2	pF
Charge carrier life time $I_F = 25\text{ mA}$	$\tau$	–	–	100	ps
Differential forward resistance $I_F = 10\text{ mA}, f = 10\text{ kHz}$	$r_f$	–	34	–	$\Omega$
Series inductance	$L_S$	–	2	–	nH

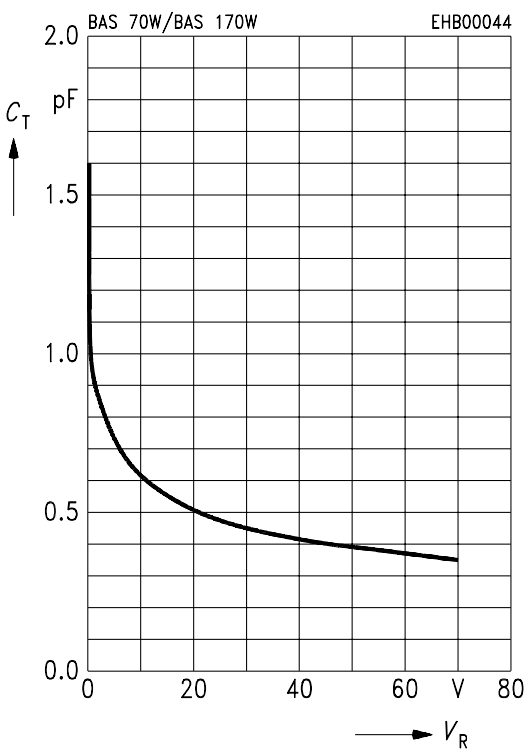
**Forward current  $I_F = f(V_F)$**



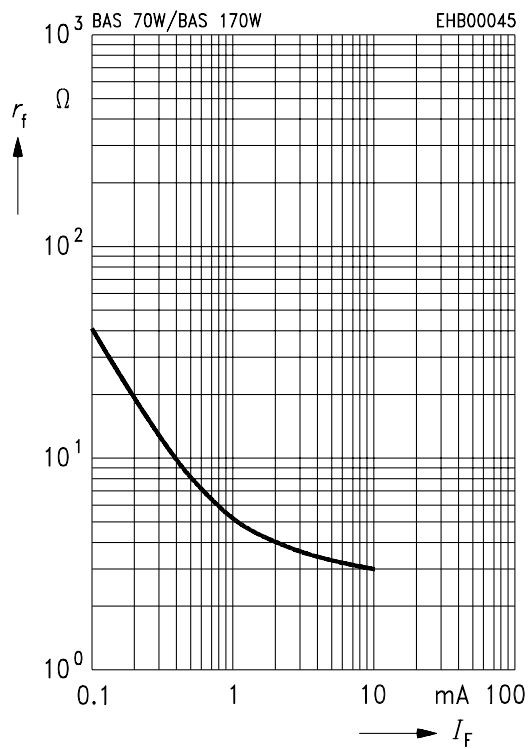
**Reverse current  $I_R = f(V_R)$**



**Diode capacitance  $C_T = f(V_R)$**

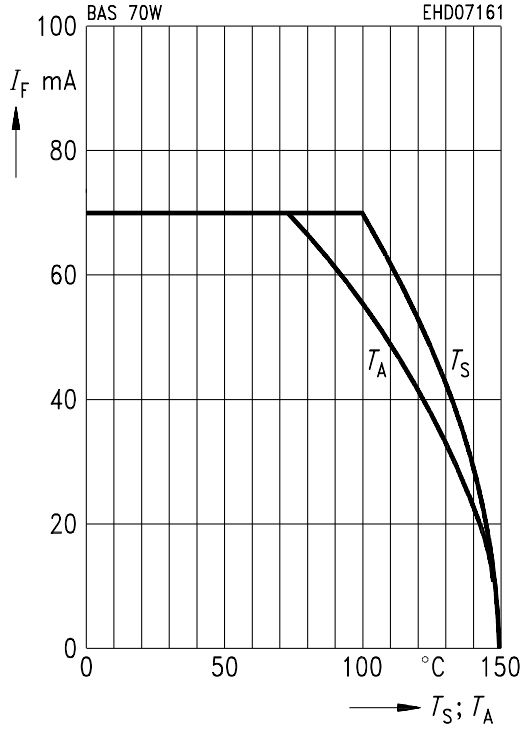


**Differential forward resistance  $R_F = f(I_F)$**

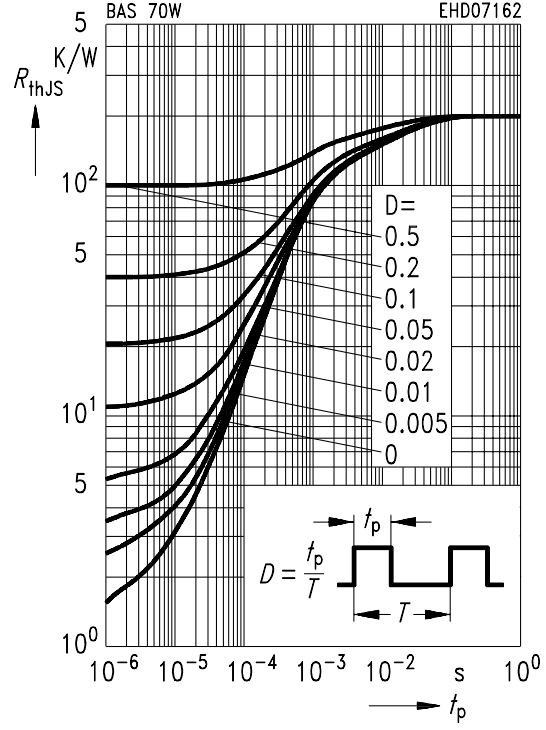


### Permissible Pulse load $I_F = f(T_A; T_S^*)$

\* Package mounted on epoxy



### Permissible load $R_{thJS} = f(t_p)$



### Permissible Pulse load $I_{Fmax} / I_{FDC} = f(t_p)$

